

Si photodiode



S9702

RGB color sensor

The S9702 is a color sensor molded into a plastic package having a 3-channel (RGB) photodiode sensitive to the blue ($\lambda p=460$ nm), green ($\lambda p=540$ nm) and red ($\lambda p=620$ nm) regions of the spectrum. The S9702 has a 3-segment (RGB) photosensitive area of $\Box 1$ mm. When compared to the previous model (S9032-02), the S9702 is significantly miniaturized (package size 55% less in cubic volume, PC board mount space 43% less in area).

Features

- **⇒** 3-channel (RGB) Si photodiode
- Surface-mount small plastic package
- Spectral response range close to the human eye sensitivity
- No sensitivity in the near IR region
- Photosensitive area: 3-segment (RGB) photosensitive area of □1 mm

Applications

- **Portable or mobile equipment**
- RGB-LCD backlight monitors
- Detectors for various light sources
- Color detection

- Absolute maximum ratings

Parameter	Symbol	Value	Unit
Reverse voltage	VR max	10	V
Operating temperature	Topr	-25 to +85	°C
Storage temperature	Tstg	-40 to +85	°C

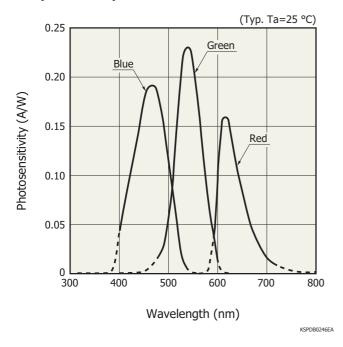
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Electrical and optical characteristics (Ta= 25 °C, per element)

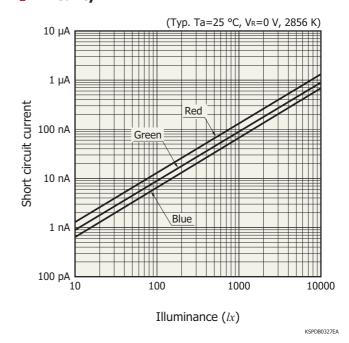
Parameter	Symbol	Con	dition	Min.	Тур.	Max.	Unit		
		Blue		-	400 to 540	-			
Spectral response range	λ	Green		-	480 to 600	-	nm		
		Red		-	590 to 720	-			
		Blue		-	460	-	nm		
Peak sensitivity wavelength	λр	Green		-	540	-			
		Red		-	620	-	-		
Photosensitivity	S	λ=λρ	Blue	0.13	0.18	-	A/W		
			Green	0.18	0.23	-			
			Red	0.11	0.16	0.16 -			
Dark current	ID	V _R =1 V All elements		-	1	50	рА		
Temperature coefficient of ID	TCID			-	1.12	-	times/°C		
Rise time	tr	VR=0 V, RL= 10 to 90%	1 kΩ	-	0.1	1.0	μs		
Terminal capacitance	Ct	VR=0 V, f=10) kHz	-	12	25	pF		

This product does not support lead-free soldering. For details on reflow soldering conditions, please contact our sales office.

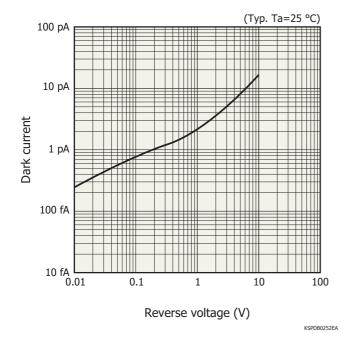
Spectral response



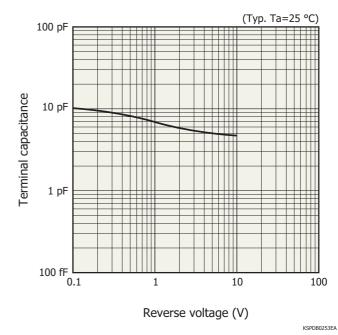
Linearity



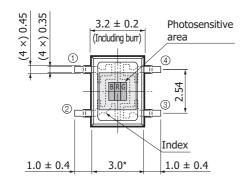
₽ Dark current vs. reverse voltage

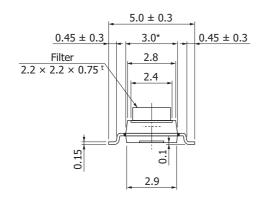


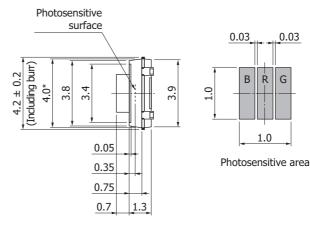
► Terminal capacitance vs. reverse voltage



Dimensional outline (uint: mm)







- ① Anode (blue)
- ② Cathode (common)
- 3 Anode (red)
- 4 Anode (green)

Tolerance unless otherwise noted: ± 0.1 , $\pm 2^{\circ}$ Shaded area indicates burr.

Chip position accuracy with respect to the package dimensions marked * X, Y≤±0.2, 0≤±2° Lead surface finish: silver plating Packing: stick (100 pcs/stick)

KSPDA0170EC

Note: If excessive vibration is continuously applied to the glass filter, there is a risk that the filter may come off, so secure the glass filter with a holder.

Line-up of RGB color sensors

Type no.	Туре	Photosensitive area (mm)	Package (mm)	Peak sensitivity wavelength (nm)		Photosensitivity					Photo		
S9032-02 Photodiode		$4 \times 4.8 \times 1.8^{t}$	В	460	В		0.18 (A/W) [λ=460 nm]						
	ф2.0	6 pin	G	540	G	0.23 (A/W) [λ=540 nm]							
			(filter 0.75 ^t)	R	620	R			/) [λ=620 nm]				
			$3 \times 4 \times 1.3^{t}$	В	460	В		0.18 (A/W) [λ=460 nm]					
S9702	Photodiode	1.0×1.0	4 pin (filter 0.75 ^t)	G	540	G		• • •		[λ=540 nm]		100	
				R	620	R		0.16 (A/W					
			$3 \times 1.6 \times 1.0^{t}$	В	460	В		,	[λ=460 nm]				
S10917-35GT Photod	Photodiode	1.0×1.0	COB	G	540	G		0.23 (A/W					
			(on-chip filter)	R	620	R		0.17 (A/W) [λ=620 nm]					
		1.0 × 1.0	$3 \times 1.6 \times 1.0^{t}$	*		В	- (, , , , , , , , , , , , , , , , , ,						
S10942-01CT Photodiod	Photodiode		COB (on-chip filter)			G							
						R	R 0.45 (A/W) [λ=640 nm]						
	Digital	1.2 × 1.2	4 × 4.8 × 1.8 ^t 6 pin (filter 0.75 ^t)	В	465	- >	В	0.21 (LSB/lx)	High R		1.9 (LSB/lx)		
S9706 photo IC				G	540	Low	G	0.45 (LSB/lx)			4.1 (LSB/lx)		
	prioto 10			R	615		R	0.64 (LSB/lx)		R	5.8 (LSB/lx)		
S11012-01CR Digital photo IC		$3.43 \times 3.8 \times 1.6^{t}$			_	В	0.3 (LSB/lx)	ے	В	2.6 (LSB/lx)	2-1		
			COB (on-chip filter)		*	Low	G	0.6 (LSB/lx)	High	G	5.3 (LSB/lx)		
	prioto ic						R	1.4 (LSB/lx)		R	12.9 (LSB/lx)		
S11059-02DT com /-03DS com	I ² C compatible	ible 0.56 × 1.22	$3 \times 4.2 \times 1.3^{t}$ 10 pin (on-chip filter)	В	460	530 615	В	4.4 (count/lx)	High	В	44.8 (count/lx)	THE RESERVE	
				G	530		G	8.3 (count/lx)		G	85.0 (count/lx)		
	color			R	615		R	11.2 (count/lx)		R	117.0 (count/lx)		
	sensor		(on chip filter)	IR	855		IR	3.0 (count/lx)		IR	30.0 (count/lx)		

^{*} Refer to the spectral response of each product's datasheet.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
 - Disclaimer
 - · Metal, ceramic, plastic package products
 - · Surface mount type products

Information described in this material is current as of February, 2016.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

AMAMATSU

www.hamamatsu.com

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184

1126-1 ICnInO-CnO, Higashi-Ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184
U.S.A.: Hamamatsu Corporation: 360 Foothill Road, Bridgewater, N.J. 08807, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-1218
Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 8152-375-0, Fax: (49) 8152-365-8
France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10
United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777
North Europe: Hamamatsu Photonics Norden AB: Torshamnsgatan 35 16440 Kista, Sweden, Telephone: (46) 8-509-031-00, Fax: (46) 8-509-031-01
Italy: Hamamatsu Photonics Italia S.r.L: Strada della Moia, 1 int. 6, 20020 Arese (Milano), Italy, Telephone: (39) 02-93581733, Fax: (39) 02-93581741
China: Hamamatsu Photonics (China) Co., Ltd.: B1201, Jiaming Center, No.27 Dongsanhuan Beilu, Chaoyang District, Beijing 100020, China, Telephone: (86) 10-6586-6006, Fax: (86) 10-6586-2866